

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S77	455	laser near6 overlap \$6 and (polysi or polycrystal\$7 near2 (si or silicon)) near15 (irradiat\$5 or laser)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 19:15
S76	546	laser near16 overlap \$6 and (polysi or polycrystal\$7 near2 (si or silicon)) near15 (irradiat\$5 or laser)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 19:15
S79	12	laser near6 overlap \$6 near10 grain and (polysi or polycrystal\$7 near2 (si or silicon)) near15 (irradiat\$5 or laser) and @py<"2004"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 19:16
S78	170	laser near6 overlap \$6 and (polysi or polycrystal\$7 near2 (si or silicon)) near15 (irradiat\$5 or laser) and @py<"2004"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 19:16
S80	41	laser near6 overlap \$6 near10 (width or wide or length) and (polysi or polycrystal \$7 near2 (si or silicon)) near15 (irradiat\$5 or laser) and @py<"2004"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:12
S82	23	yun near2 ho near2 jung.in. and laser near4 anneal\$5 and overlap\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:27
S81	36	yun near2 ho near2 jung.in. and laser near4 anneal\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:27

S87	707	".mu.m" near14 overlap\$5 and laser near4 anneal\$5 and amorphous and (tft or transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:43
S86	711	".mu.m" near14 overlap\$5 and laser near4 anneal\$5 and amorphous	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:43
S85	747	".mu.m" near14 overlap\$5 and laser near4 anneal\$5 and overlap\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:43
S84	2199	".mu.m" near14 width and laser near4 anneal\$5 and overlap\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:43
S83	4102	".mu.m" and laser near4 anneal\$5 and overlap\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:43
S90	53	".mu.m" near4 overlap\$5 same (beam or laser) and laser near4 anneal \$5 and amorphous and (tft or transistor) and @py<"2005"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:44
S89	113	".mu.m" near4 overlap\$5 and laser near4 anneal\$5 and amorphous and (tft or transistor) and @py<"2005"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:44
S88	245	".mu.m" near4 overlap\$5 and laser near4 anneal\$5 and amorphous and (tft or transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:44

S91	50	".mu.m" near4 overlap\$5 near15 (beam or laser) and laser near4 anneal \$5 and amorphous and (tft or transistor) and @py<"2005"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:45
S92	3	".mu.m" near4 translat\$5 near15 (beam or laser) and laser near4 anneal \$5 and amorphous and (tft or transistor) and @py<"2005"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:47
S93	1336	("mu.m" or micrometer) near14 width and laser near4 anneal\$5 and amorphous and (tft or transistor) and @py<"2005"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:55
S94	3	("mu.m" or micrometer) near14 width near15 translat\$5 and laser near4 anneal\$5 and amorphous and (tft or transistor) and @py<"2005"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 21:56
S96	1	"6555449".pn. and transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:06
S95	0	"6555449".pn. and tft	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:06
S97	88	james near2 im.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:11

S102	23	james near2 im.in. and lateral near2 solidification and (". mu.m" or micrometer) near14 width and (tft or transistor) and amorphous	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:12
S101	23	james near2 im.in. and lateral near2 solidification and (". mu.m" or micrometer) near14 width and (tft or transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:12
S100	33	james near2 im.in. and lateral near2 solidification and (". mu.m" or micrometer) near14 width	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:12
S99	44	james near2 im.in. and lateral near2 solidification and (". mu.m" or micrometer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:12
S98	70	james near2 im.in. and lateral near2 solidification	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:12
S103	20	james near2 im.in. and lateral near2 solidification and (". mu.m" or micrometer) near14 width and (tft) and amorphous	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:19
S107	47	tft near10 display and lateral near2 solidification and @py<"2004"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:27
S106	478	tft near10 display and lateral near2 solidification	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:27

S105	43186	tft near10 display	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:27
S104	45877	tft near14 display	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/17 22:27
S110	6	(thin near2 film near2 transistor or tft) near10 display near15 lateral near2 solidification and @py<"2004"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/18 22:39
S109	16	(thin near2 film near2 transistor or tft near10 display) near15 lateral near2 solidification and @py<"2004"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/18 22:39
S108	83	(thin near2 film near2 transistor or tft near10 display) and lateral near2 solidification and @py<"2004"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/18 22:39
S111	16	"0118854"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/18 22:53
L1	42	(ji near2 yong near2 park or hye near2 park).in. and sls	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/19 12:00

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